

15.0A Surface Mount Schottky Barrier Rectifiers

0.026(0.65)

0.151(3.85) 0.128(3.25) 0.026(0.65)

0.017(0.45)

 $\underbrace{\begin{array}{c} 0.\ 076\ (1.\ 95) \\ \hline 0.\ 065\ (1.\ 65) \\ \hline \end{array}}_{0.\ 065\ (1.\ 65)}$

Case: TO-277B

♦ 0.075(1.9)

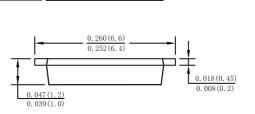
0.067(1.7)

Features

- · Schottky Barrier Chip
- · High Thermal Reliability
- · Patented Super Barrier Rectifier Technology
- \cdot High Forward Surge Capability
- \cdot Ultra Fow Power Loss,High Efficiency
- · Excellent High Temperature Stability
- · Plastic material-UL flammability 94V-0

Mechanical Data

- · Case: TO-277B, molded plastic
- Terminals:Plated Leads Solderable per MIL-STD-202,Method 208
- · Meet MSL level 1,per J-STD-020, LF Maximum peak of 260 ℃
- Polarity:Cathode Band
- Mounting Position:Any
- Marking:Type Number
- · Lead Free:For RoHS/Lead Free Version



0.216(5.5)

0.209(5.3)

dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics @T_A =25 °C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

0.165(4.2)

0.150(3.8)

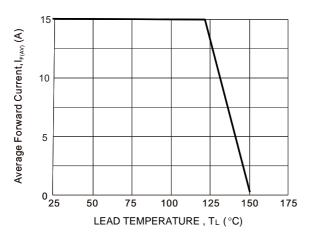
Parameter	Symbol	SB154	SB1545L	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC blocking voltage	V _{RRM} V _{RWM} V _{DC}	45		V
RMS Rectified Voltage	V _{R(RMS)}	32	32	
Average Rectified Output Current (Note1)	IF(AV)	15.0		А
Non-Repetitive Peak Forward Surge8.3ms Single Half Sine-Wave Superimposed on rated load(JEDEC Method) (Note2)	IFSM	250		А
I ² t Rating for Fusing (t < 8.3ms)	l ² t	259.375		A ² s
Forward Voltage Drop $T_A = 25 \ ^{\circ}C \ @IF = 1A$ $T_A = 25 \ ^{\circ}C \ @IF = 5A$ $T_A = 25 \ ^{\circ}C \ @IF = 10A$ $T_A = 25 \ ^{\circ}C \ @IF = 15A$	Vfm	Typ. 0.29 0.37 0.42 0.47	Max. - 0.47 0.52	v
Peak Reverse Curent $T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $T_A = 100^{\circ}C$	R	0.3 15		mA
Typical Thermal Resistance Junctionto Ambient	Reja Rejl	110 3.5		°C/W
Operating junction temperature range	TJ	-55 to +150		°C
storage temperature range	Тѕтс	-55 to +150		°C

Note:1.Valid Provided that are kept at ambient temperature at a distance of 9.5mm from the case.

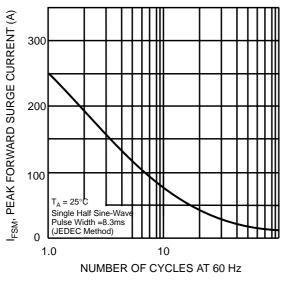
2.Fr-4pcb.2oz.Copper, minimum recommend pad layout .18.8mm×14.4.Anode pad dimensions 5.6mm×14.4mm.



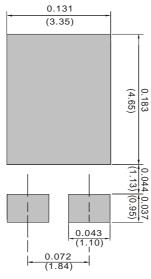
Fig.1 - Forward Current Derating Curve











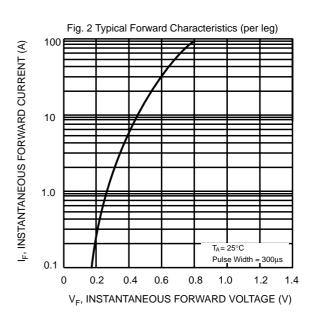
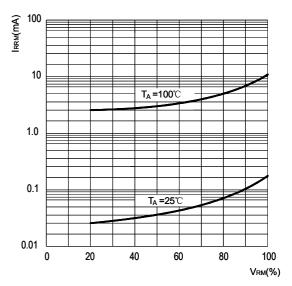


Fig4: Typical Reverse Characteristics





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